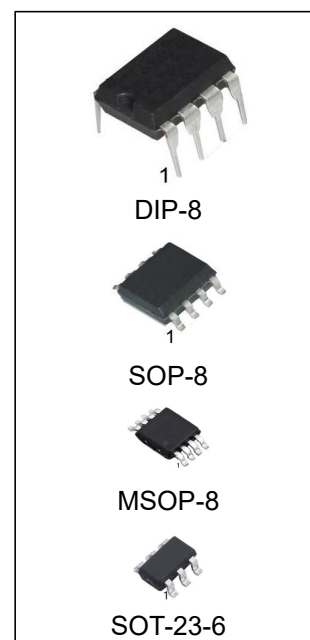


Low Voltage Reference

Features

- Output Voltage: 2.5 V $\pm$ 25 mV
- Input Voltage Range: 4.5 V to 40 V
- Quiescent Current: 1.2 mA Typical
- Output Current: 10 mA
- Temperature Coefficient: 10 ppm/ $^{\circ}$ C Typical
- Guaranteed Temperature Drift Specification
- Equivalent to AD580
- Standard DIP-8, SOP-8, MSOP-8 and SOT-23-6 Package



Ordering Information

DEVICE	Package Type	MARKING	Packing	Packing Qty
MC1403N	DIP-8	MC1403	TUBE	2000pcs/box
MC1403M/TR	SOP-8	MC1403	REEL	2500pcs/reel
MC1403MM/TR	MSOP-8	1403	REEL	3000pcs/reel
MC1403M6/TR	SOT-23-6	1403	REEL	3000pcs/reel
MC1403BN	DIP-8	MC1403B	TUBE	2000pcs/box
MC1403BM/TR	SOP-8	MC1403B	REEL	2500pcs/reel
MC1403BMM/TR	MSOP-8	1403B	REEL	3000pcs/reel
MC1403BM6/TR	SOT-23-6	1403B	REEL	3000pcs/reel

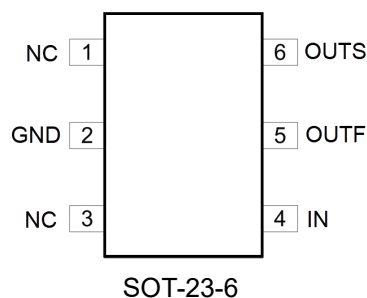
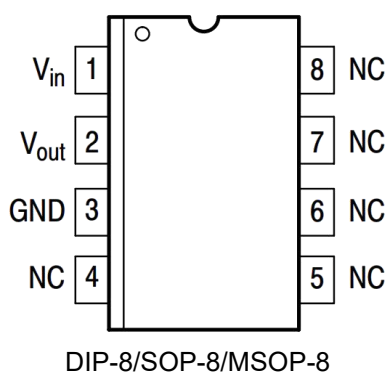
General Description

A precision band-gap voltage reference designed for critical instrumentation and D/A converter applications. This unit is designed to work with D/A converters, up to 12 bits in accuracy, or as a reference for power supply applications.

Typical Applications

- Voltage Reference for 8 to 12 Bit D/A Converters
- Low TC Zener Replacement
- High Stability Current Reference
- Voltmeter System Reference
- Pb-Free Package is Available

Pin Connections



Maximum Ratings (TA = 25°C, unless otherwise noted.)

Rating		Symbol	Value	Unit
Input Voltage		V _I	40	V
Storage Temperature		T _{stg}	-65 to 150	°C
Junction Temperature		T _J	+175	°C
Operating Ambient Temperature Range	MC1403B	T _A	-40 to +85	°C
	MC1403		0 to +70	°C
Lead Temperature (Soldering, 10 seconds)		T _L	260	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

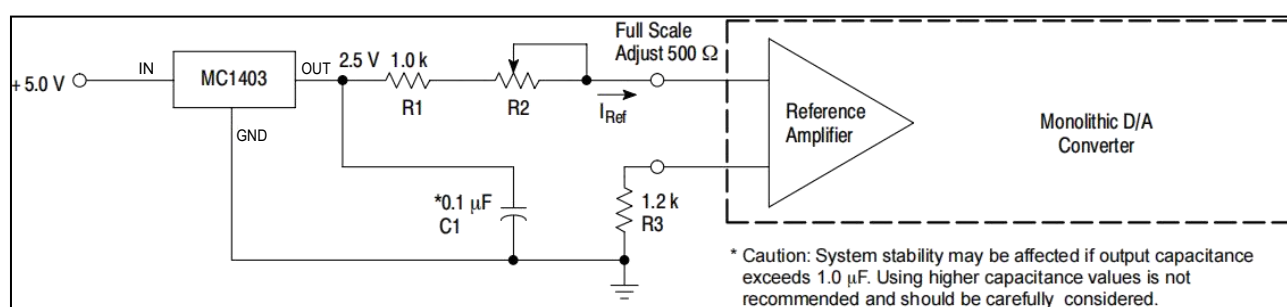


Figure 1. A Reference for Monolithic D/A Converters

**Providing the Reference Current
for ON Semiconductor Monolithic D/A Converters**

The MC1403 makes an ideal reference for many monolithic D/A converters, requiring a stable current reference of nominally 2.0 mA. This can be easily obtained from the MC1403 with the addition of a series resistor, R1. A variable resistor, R2, is recommended to provide means for full-scale adjust on the D/A converter.

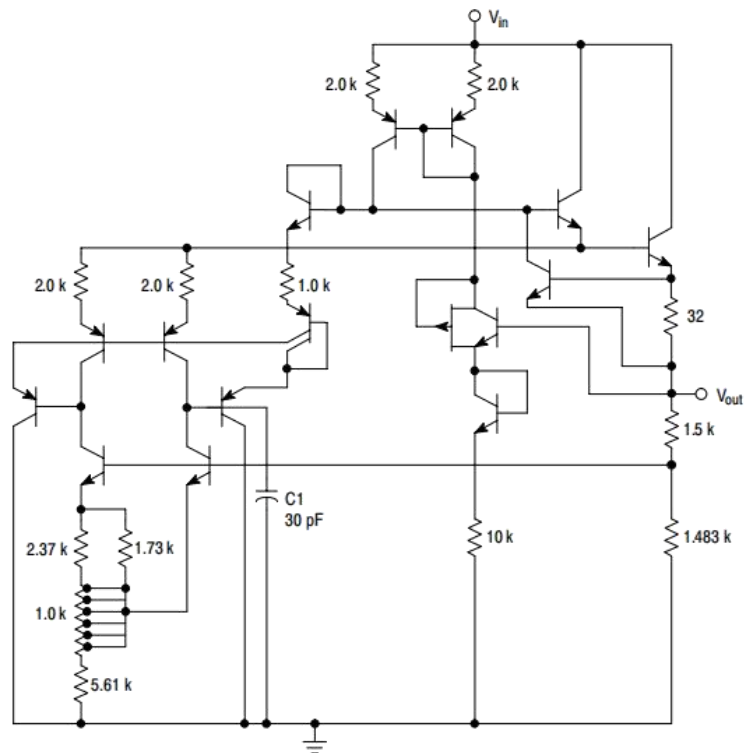
The resistor R3 improves temperature performance by matching the impedance on both inputs of the D/A reference amplifier. The capacitor decouples any noise present on the reference line. It is essential if the D/A converter is located any appreciable distance from the reference.

A single MC1403 reference can provide the required current input for up to five of the monolithic D/A converters.

Electrical Characteristics ($V_{in} = 15\text{ V}$, $T_A = 25^\circ\text{C}$, unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
Output Voltage ($I_O = 0\text{ mA}$)	V_{out}	2.475	2.5	2.525	V
Temperature Coefficient of Output Voltage* MC1403	$\Delta V_O / \Delta T$	—	10	40	ppm/ $^\circ\text{C}$
Output Voltage Change* (Over specified temperature range)	ΔV_O				mV
MC1403 0 to $+70^\circ\text{C}$		—	—	7.0	
MC1403B -40 to $+85^\circ\text{C}$		—	—	12.5	
Line Regulation ($I_O = 0\text{ mA}$) ($15\text{ V} \leq V_I \leq 40\text{ V}$) ($4.5\text{ V} \leq V_I \leq 15\text{ V}$)	Regline	—	1.2 0.6	4.5 3.0	mV
Load Regulation ($0\text{ mA} < I_O < 10\text{ mA}$)	Regload	—	—	10	mV
Quiescent Current ($I_O = 0\text{ mA}$)	I_Q	—	1.2	1.5	mA

*Guaranteed but not tested.



This device contains 15 active transistors.

Figure 2. MC1403, B Schematic

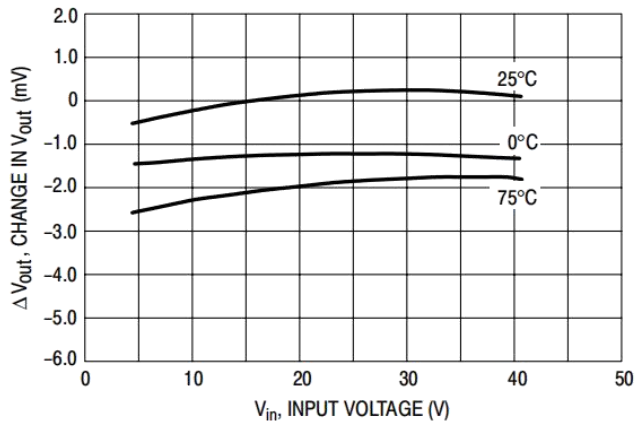


Figure 3. Typical Change in Vout versus Vin
(Normalized to Vin = 15 V @ TC = 25°C)

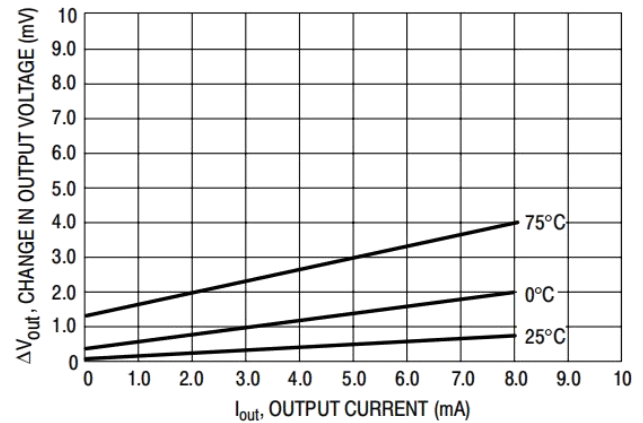


Figure 4. Change in Output Voltage v
ersus Load Current
(Normalized to Vout @ Vin = 15 V, Iout = 0 mA)

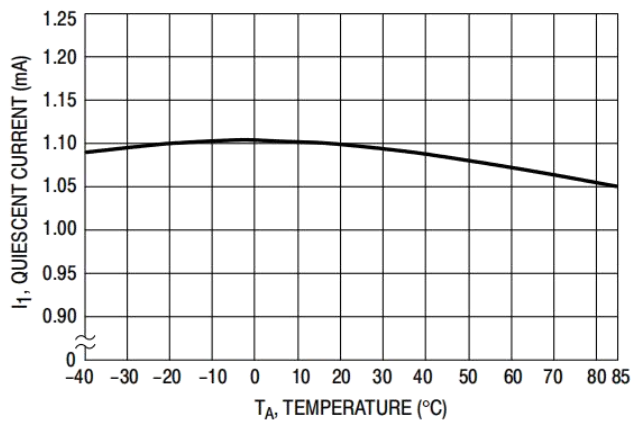


Figure 5. Quiescent Current versus Temperature
(Vin = 15 V, Iout = 0 mA)

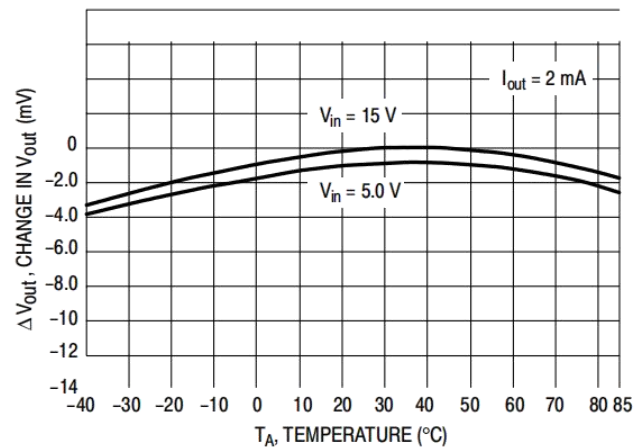


Figure 6. Change in Vout versus
Temperature(Normalized to Vout @ Vin = 15 V)

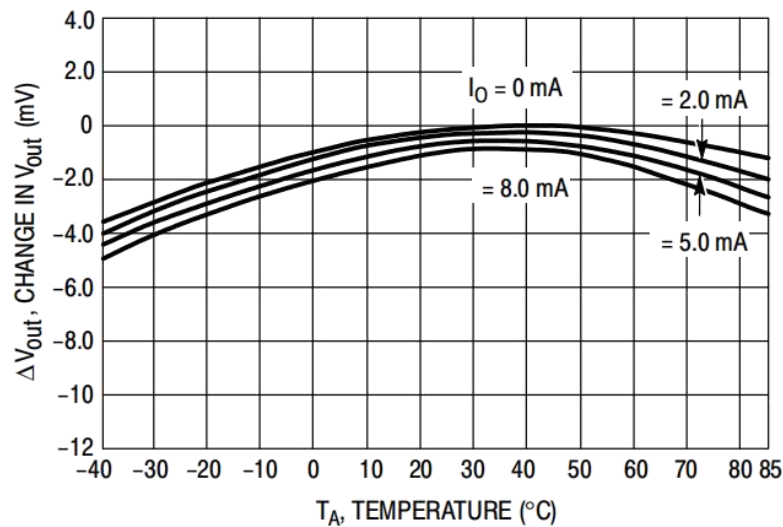


Figure 7. Change in Vout versus Temperature
(Normalized to TA = 25°C, Vin = 15 V, Iout = 0 mA)

3-1/2-Digit Voltmeter – Common Anode Displays, Flashing Overrange

An example of a 3-1/2-digit voltmeter using the MC14433 is shown in the circuit diagram of Figure 8. The reference voltage for the system uses an MC1403 2.5 V reference IC. The full scale potentiometer can calibrate for a full scale of 199.9 mV or 1.999 V. When switching from 2.0 V to 200 mV operation, R_I is also changed, as shown on the diagram.

When using RC equal to 300 k Ω , the clock frequency for the system is about 66 kHz. The resulting conversion time is approximately 250 ms.

When the input is overrange, the display flashes on and off. The flashing rate is one-half the conversion rate. This is done by dividing the EOC pulse rate by 2 with 1/2 MC14013B flip-flop and blanking the display using the blanking input of the MC14543B.

The display uses an LED display with common anode digit lines driven with an MC14543B decoder and an MC1413 LED driver. The MC1413 contains 7 Darlington transistor drivers and resistors to drive the segments of the display. The digit drive is provided by four MPS-A12 Darlington transistors operating in an emitter-follower configuration. The MC14543B, MC14013B and LED displays are referenced to VEE via Pin 13 of the MC14433. This places the full power supply voltage across the display. The current for the display may be adjusted by the value of the segment resistors shown as 150 Ω in Figure 8.

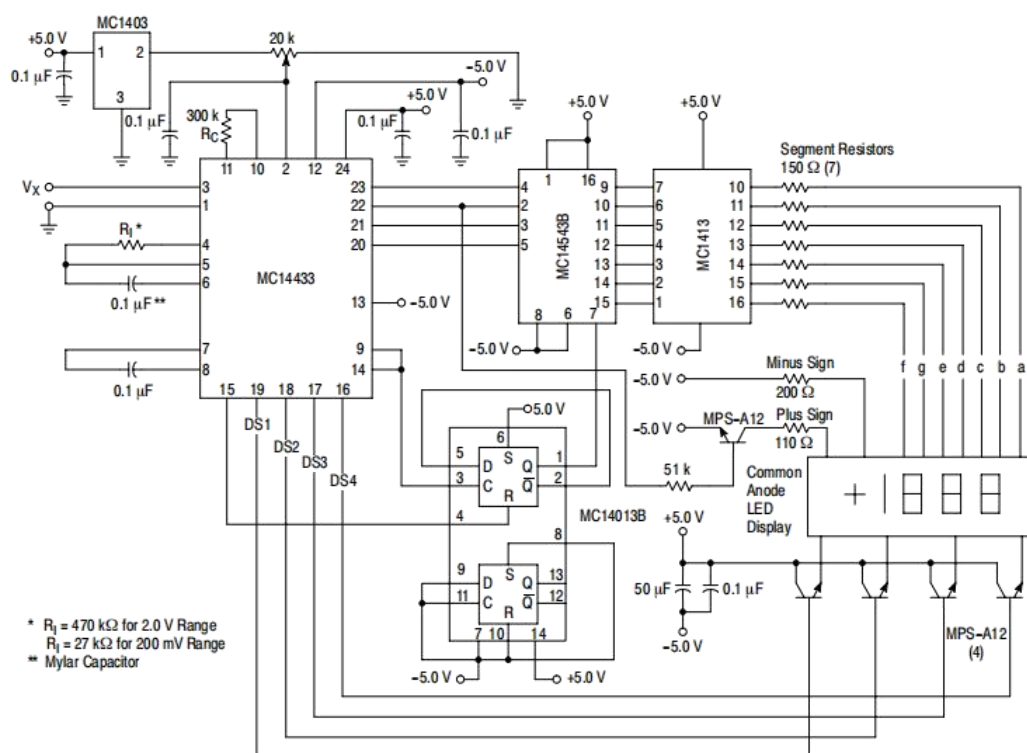
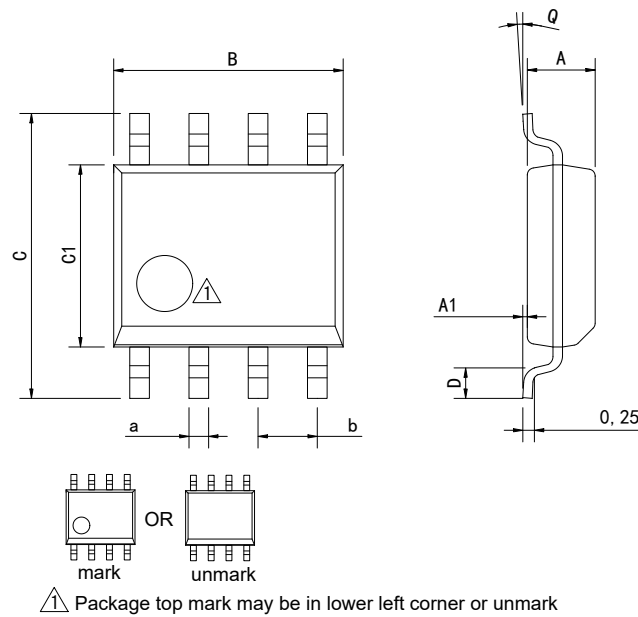


Figure 8. 3-1/2-Digit Voltmeter

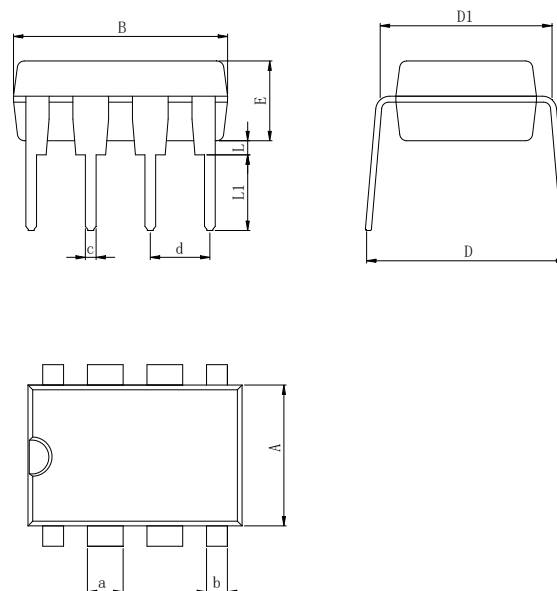
Physical Dimensions

SOP-8



Dimensions In Millimeters(SOP-8)									
Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	1.35	0.05	4.90	5.80	3.80	0.40	0°	0.35	1.27 BSC
Max:	1.55	0.20	5.10	6.20	4.00	0.80	8°	0.45	

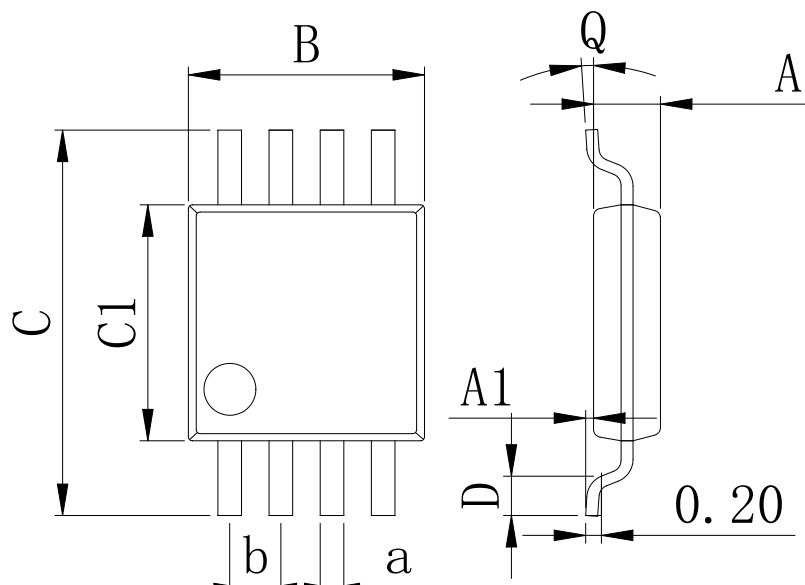
DIP-8



Dimensions In Millimeters(DIP-8)											
Symbol:	A	B	D	D1	E	L	L1	a	b	c	d
Min:	6.10	9.00	8.10	7.42	3.10	0.50	3.00	1.50	0.85	0.40	2.54 BSC
Max:	6.68	9.50	10.9	7.82	3.55	0.70	3.60	1.55	0.90	0.50	

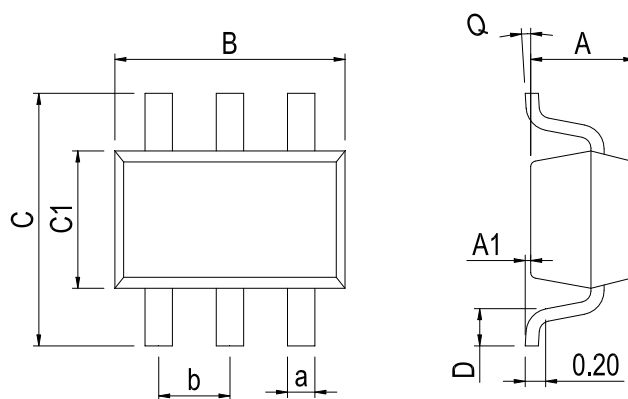
Physical Dimensions

MSOP-8



Dimensions In Millimeters(MSOP-8)									
Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	0.80	0.05	2.90	4.75	2.90	0.35	0°	0.25	0.65 BSC
Max:	0.90	0.20	3.10	5.05	3.10	0.75	8°	0.35	

SOT-23-6



Dimensions In Millimeters(SOT-23-6)									
Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	1.00	0.00	2.82	2.65	1.50	0.30	0°	0.30	0.95 BSC
Max:	1.15	0.15	3.02	2.95	1.70	0.60	8°	0.50	

Revision History

REVISION NUMBER	DATE	REVISION	PAGE
V1.0	2015-7	New	1-10
V1.1	2018-8	Update encapsulation type、Updated DIP-8 dimension	1、 7
V1.2	2024-11	Update Lead Temperature	3
V1.3	2025-12	Update important statements、 Update SOP-8 Dimension drawing	7、 10
V1.4	2026-4	Add SOT-23-6 package	1

IMPORTANT STATEMENT:

Huaguan Semiconductor reserves the right to change products and services offered without prior notice. Customers should obtain the latest relevant information before placing orders and verify that such information is current and complete. Huaguan Semiconductor assumes no responsibility or liability for altered documents.

Customers are responsible for complying with safety standards and implementing safety measures when using Huaguan Semiconductor products in system design and end-product manufacturing. You assume full responsibility for: selecting the appropriate Huaguan Semiconductor products for your application; designing, validating, and testing your application; and ensuring that your application complies with applicable standards and all other safety, security, or other requirements. This is to prevent potential risks that may lead to personal injury or property damage.

Huaguan Semiconductor products are not approved for use in life support, military, aerospace, or other high-risk applications. Huaguan products are neither intended nor warranted for use in such systems or equipment. Any failure or malfunction may lead to personal injury or severe property damage. Such applications are deemed "Unsafe Use." Unsafe Use includes, but is not limited to: surgical and medical equipment, nuclear energy control equipment, aircraft or spacecraft instruments, control or operation of vehicle power, braking, or safety systems, traffic signal instruments, all types of safety devices, and any other applications intended to support or sustain life. Huaguan Semiconductor shall not be liable for consequences resulting from Unsafe Use in these fields. Users must independently evaluate and assume all risks. Any issues, liabilities, or losses arising from the use of products beyond their approved applications shall be solely borne by the user. Users may not claim any compensation from Huaguan Semiconductor based on these terms. If any third party claims against Huaguan Semiconductor due to such Unsafe Use, the user shall compensate Huaguan Semiconductor for all resulting damages and liabilities.

Huaguan Semiconductor provides technical and reliability data (including datasheets), design resources (including reference designs), application or other design advice, web tools, safety information, and other resources for its semiconductor products. However, no guarantee is made that these resources are free from defects, and no express or implied warranties are provided. The use of testing and other quality control techniques is limited to Huaguan Semiconductor's quality assurance scope. Not all parameters of each device are tested.

Huaguan Semiconductor's documentation authorizes you to use these resources only for developing applications related to the products described herein. You are not granted rights to any other intellectual property of Huaguan Semiconductor or any third party. Any other reproduction or display of these resources is strictly prohibited. You shall fully indemnify Huaguan Semiconductor and its agents against any claims, damages, costs, losses, and liabilities arising from your use of these resources. Huaguan Semiconductor shall not be held responsible.